

# MCR101-MCR104 SERIES

## SILICON CONTROLLED RECTIFIERS

### FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

### MAXIMUM RATINGS

| Rating                                                                                            | Symbol      | Value                 | Unit             |
|---------------------------------------------------------------------------------------------------|-------------|-----------------------|------------------|
| <b>Peak reverse blocking voltage</b><br>MCR101<br>MCR102<br>MCR103<br>MCR104                      | $V_{RRM}$   | 15<br>30<br>60<br>100 | Volts            |
| <b>Forward current RMS</b> (all conduction angles)                                                |             | 0.8                   |                  |
| <b>Peak forward surge current</b> (1/2 cycle, sine wave 60 Hz, $T_A = 25^\circ\text{C}$ )         |             | 6.0                   |                  |
| <b>Circuit fusing considerations</b> ( $t = 1$ to 8.3ms, $T_A = 25^\circ\text{C}$ )               |             | 0.15                  |                  |
| <b>Forward peak gate power</b> ( $T_A = 25^\circ\text{C}$ )                                       | $P_{GM}$    | 0.1                   | Watts            |
| <b>Forward average gate power</b> ( $T_A = 25^\circ\text{C}$ )                                    | $P_{G(AV)}$ | 0.01                  | Watts            |
| <b>Forward peak gate current</b> ( $T_A = 25^\circ\text{C}$ , 300 $\mu\text{s}$ , 120PPS)         | $I_{GM}$    | 1.0                   | Amps             |
| <b>Reverse peak gate voltage</b>                                                                  | $V_{GM}$    | 4.0                   | Volts            |
| <b>Operating junction temperature range @ rated <math>V_{RRM}</math> and <math>V_{DRM}</math></b> | $T_J$       | -65 to +85            | $^\circ\text{C}$ |
| <b>Storage temperature range</b>                                                                  | $T_{stg}$   | -65 to +150           | $^\circ\text{C}$ |
| <b>Lead solder temperature</b> (<1/16" from case, 10 sec. max.)                                   | -           | +230                  | $^\circ\text{C}$ |

### THERMAL CHARACTERISTICS

| Characteristic                                 | Symbol          | Max | Unit               |
|------------------------------------------------|-----------------|-----|--------------------|
| <b>Thermal resistance, junction-to-case</b>    | $R_{\theta JC}$ | 75  | $^\circ\text{C/W}$ |
| <b>Thermal resistance, junction-to-ambient</b> | $R_{\theta JA}$ | 200 | $^\circ\text{C/W}$ |

### ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)

| Characteristic                                                                                                                                                                  | Symbol                   | Min                   | Max              | Unit          |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------|-----------------------|------------------|---------------|
| <b>Peak forward blocking voltage</b> <sup>(1)</sup> ( $T_C = 85^\circ\text{C}$ )<br>MCR101<br>MCR102<br>MCR103<br>MCR104                                                        | $V_{DRM}$                | 15<br>30<br>60<br>100 | -<br>-<br>-<br>- | Volts         |
| <b>Peak forward blocking current</b> (Rated $V_{DRM}$ @ $T_C = 85^\circ\text{C}$ )                                                                                              |                          | -                     | 100              |               |
| <b>Peak reverse blocking current</b> (Rated $V_{RRM}$ @ $T_C = 85^\circ\text{C}$ )                                                                                              |                          | -                     | 100              |               |
| <b>Forward "on" voltage</b> <sup>(2)</sup> ( $I_{TM} = 1.0\text{A}$ peak @ $T_A = 25^\circ\text{C}$ )                                                                           |                          | -                     | 1.7              |               |
| <b>Gate trigger current</b> (continuous dc) <sup>(3)</sup> ( $V_{AK} = 7\text{Vdc}$ , $R_L = 100\Omega$ , $T_C = 25^\circ\text{C}$ )                                            | $I_{GT}$                 | -                     | 200              | $\mu\text{A}$ |
| <b>Gate trigger voltage</b> (continuous dc) ( $V_{AK} = 7\text{Vdc}$ , $R_L = 100\Omega$ )<br>$T_C = 25^\circ\text{C}$<br>$T_C = -65^\circ\text{C}$<br>$T_C = 85^\circ\text{C}$ | $V_{GT}$<br><br>$V_{GD}$ | -<br>-<br>0.1         | 0.8<br>1.2<br>-  | Volts         |
| <b>Holding current</b> ( $V_{AK} = 7\text{Vdc}$ , initiating current = 20mA)<br>$T_C = 25^\circ\text{C}$<br>$T_C = -65^\circ\text{C}$                                           | $I_H$                    | -<br>-                | 5.0<br>10        |               |
|                                                                                                                                                                                 |                          |                       |                  |               |

## MCR101-MCR104 SERIES

### SILICON CONTROLLED RECTIFIERS

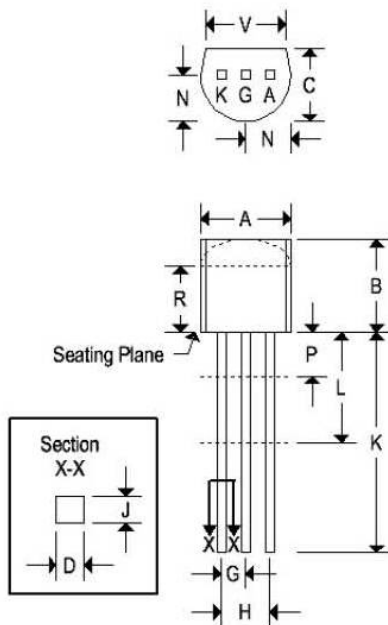
Note 1:  $V_{DRM}$  and  $V_{RRM}$  for all types can be applied on a continuous dc basis without incurring damage. Ratings apply for zero or negative gate voltage but positive gate voltage shall not be applied concurrently with a negative potential on the anode. When checking forward or reverse blocking capability, thyristor devices should not be tested with a constant current source in a manner that the voltage applied exceeds the rated blocking voltage.

Note 2: Forward current applied for 1.0 ms maximum duration, duty cycle  $\leq 1.0\%$ .

Note 3:  $R_{GK}$  current is not included in measurement.

#### MECHANICAL CHARACTERISTICS

|                 |                             |
|-----------------|-----------------------------|
| <b>Case:</b>    | TO-92                       |
| <b>Marking:</b> | Body painted, alpha-numeric |
| <b>Pin out:</b> | See below                   |

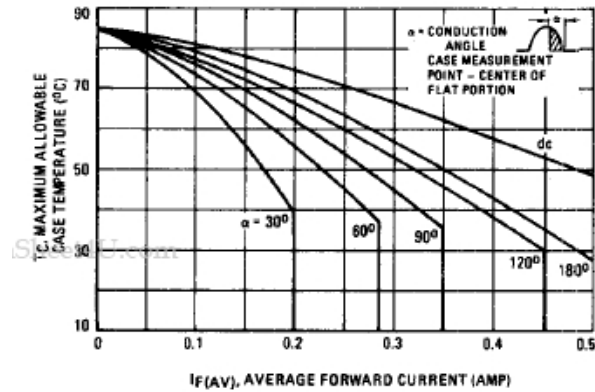


|   | TO-92  |       |             |       |
|---|--------|-------|-------------|-------|
|   | Inches |       | Millimeters |       |
|   | Min    | Max   | Min         | Max   |
| A | 0.175  | 0.205 | 4.450       | 5.200 |
| B | 0.170  | 0.210 | 4.320       | 5.330 |
| C | 0.125  | 0.165 | 3.180       | 4.190 |
| D | 0.016  | 0.022 | 0.410       | 0.550 |
| F | 0.016  | 0.019 | 0.410       | 0.480 |
| G | 0.045  | 0.055 | 1.150       | 1.390 |
| H | 0.095  | 0.105 | 2.420       | 2.660 |
| J | 0.015  | 0.020 | 0.390       | 0.500 |
| K | 0.500  | -     | 12.700      | -     |
| L | 0.250  | -     | 6.350       | -     |
| N | 0.080  | 0.105 | 2.040       | 2.660 |
| P | -      | 0.100 | -           | 2.540 |
| R | 0.115  | -     | 2.930       | -     |
| V | 0.135  | -     | 3.430       | -     |

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### SILICON CONTROLLED RECTIFIERS

**FIGURE 1 – CURRENT DERATING  
(REFERENCE: CASE TEMPERATURE)**



**FIGURE 2 – CURRENT DERATING  
(REFERENCE: AMBIENT TEMPERATURE)**

